NSN 5961-01-132-8065

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-132-8065 **Inclosure Material:** Metal **Overall Length:** 0.070 inches **Overall Diameter:** 0.122 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, dc **Current Rating Per Characteristic:** 0.02 microamperes forward current, average peak **Precious Material And Location:** Leads gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No Fiig: A110a0